

1.5V Drive Pch MOSFET

RW1A013ZP

●Structure

Silicon P-channel MOSFET

Features

- 1) Low on-resistance.
- 2) High power package.
- 3) Low voltage drive. (1.5V)

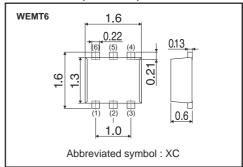
Application

Switching

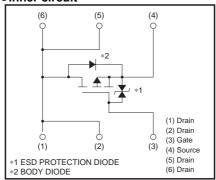
Packaging specifications

	Package	Taping	
Type	Code	T2R	
	Basic ordering unit (pieces)	8000	
RW1A013ZP		0	

●Dimensions (Unit : mm)



•Inner circuit



●Absolute maximum ratings (Ta=25°C)

Parameter		Symbol		Limits	Unit	
Drain-source voltage		VDSS		-12	V	
Gate-source voltage		V _{GSS}		±10	V	
Drain current	Continuous	ΙD		±1.3	А	
	Pulsed	I _{DP}	*1	±2.6	Α	
Source current	Continuous	Is		-0.5	Α	
(Body diode)	Pulsed	I _{SP}	*1	-2.6	Α	
Total power dissipation		PD	*2	0.7	W	
Channel temperature		Tch		150	°C	
Range of Storage temperature		Tstg		-55 to +150	°C	

Thermal resistance

Parameter	Symbol	Limits	Unit
Channel to ambient	Rth(ch-a) *	179	°C / W

^{*} When mounted on a ceramic board

^{*1} Pw≤10μs, Duty cycle≤1% *2 When mounted on a ceramic board

RW1A013ZP Data Sheet

●Electrical characteristics (Ta=25°C)

Parameter	Symbol	Min.	Тур.	Max.	Unit	Conditions	
Gate-source leakage	Igss	_	-	±10	μΑ	Vgs=±10V, Vps=0V	
Drain-source breakdown voltage	V _{(BR) DSS}	-12	_	_	V	I _D = -1mA, V _{GS} =0V	
Zero gate voltage drain current	IDSS	_	_	-1	μΑ	V _{DS} = -12V, V _{GS} =0V	
Gate threshold voltage	V _{GS (th)}	-0.3	-	-1.0	V	V_{DS} = -6V, I_{D} = -1mA	
Static drain-source on-state resistance		_	190	260	mΩ	I _D = -1.3A, V _G S= -4.5V	
	B*	_	280	390	mΩ	I _D = -0.6A, V _G S= -2.5V	
	R _{DS} (on)	1	400	600	mΩ	I _D = -0.6A, V _G S= -1.8V	
		-	530	1060	mΩ	I _D = -0.2A, V _G S= -1.5V	
Forward transfer admittance	Y _{fs} *	1.4	-	-	S	V _{DS} = -6V, I _D = -1.3A	
Input capacitance	Ciss	-	290	_	pF	V _{DS} = -6V	
Output capacitance	Coss	_	28	_	pF	V _{GS} =0V	
Reverse transfer capacitance	Crss	_	21	_	pF	f=1MHz	
Turn-on delay time	t _{d (on)} *	_	8	_	ns	V _{DD} ≒ −6V	
Rise time	tr *	_	10	_	ns	ID= -0.6A	
Turn-off delay time	t _{d (off)} *	_	30	_	ns	Vgs= −4.5V Ri≒ 10Ω	
Fall time	t _f *	_	9	_	ns	R _G =10Ω	
Total gate charge	Qg *	_	2.4	_	nC	V _{DD} ≒-6V R _L ≒4.6Ω	
Gate-source charge	Qgs *	_	0.6	_	nC	I _D =-1.3A R _G =10Ω	
Gate-drain charge	Q _{gd} *	_	0.4	_	nC	V _{GS} = -4.5V	

^{*}Pulsed

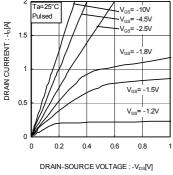
●Body diode characteristics (Source-drain) (Ta=25°C)

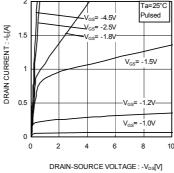
Parameter	Symbol	Min.	Тур.	Max.	Unit	Conditions
Forward voltage	Vsp *	_	_	-1.2	V	Is= -1.3A, Vgs=0V

^{*}Pulsed

RW1A013ZP **Data Sheet**

Electrical characteristics





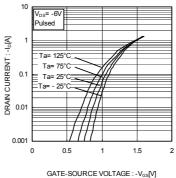
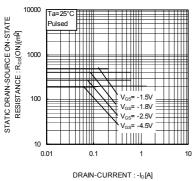


Fig.1 Typical Output Characteristics(I)

Fig.2 Typical Output Characteristics(${\rm I\hspace{-.1em}I}$)

Fig.3 Typical Transfer Characteristics



10000 STATIC DRAIN-SOURCE ON-STATE $\begin{array}{c} \text{RESISTANCE}: R_{DS}(ON)[m\Omega] \\ \\ 00 \\ \\ \end{array}$ Ta=125°C Ta=75°C Ta=25°C Ta= -25°C 0.01 0.1 DRAIN-CURRENT : -I_D[A]

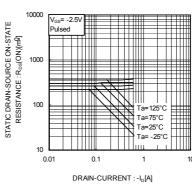
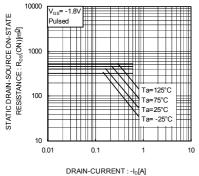
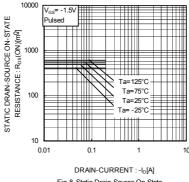


Fig.4 Static Drain-Source On-State Resistance vs. Drain Current(I)

Fig.5 Static Drain-Source On-State Resistance vs. Drain Current(II)

Fig.6 Static Drain-Source On-State Resistance vs. Drain Current(Ⅲ)





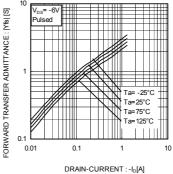
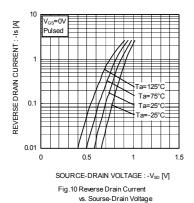
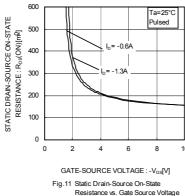


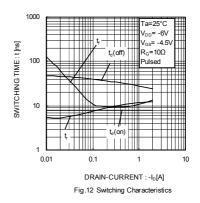
Fig.7 Static Drain-Source On-State Resistance vs. Drain Current(Ⅳ)

Fig.8 Static Drain-Source On-State Resistance vs. Drain Current(V)

Fig.9 Forward Transfer Admittance vs. Drain Current

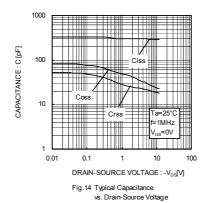






5 | Ta=25°C | Ta

Fig.13 Dynamic Input Characteristics



Measurement circuits

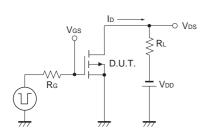


Fig.1-1 Switching time measurement circuit

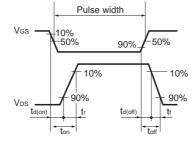


Fig.1-2 Switching waveforms

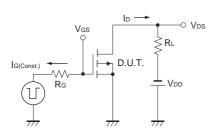


Fig.2-1 Gate charge measurement circuit

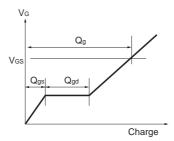


Fig.2-2 Gate charge waveform

Notice

This product might cause chip aging and breakdown under the large electrified environment . Please consider to design ESD protection circuit.

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